P/ ENT COOPERATION TREAT

PCT To: Commissioner US Department of Commerce

(PCT Rule 61.2)

US Department of Commerce United States Patent and Trademark Office, PCT 2011 South Clark Place Room CP2/5C24 Arlington, VA 22202 ETATS-UNIS D'AMERIQUE

Date of mailing (day/month/year)

04 July 2001 (04.07.01)

International application No.
PCT/US00/21377

International filing date (day/month/year)
04 August 2000 (04.08.00)

Applicant

MOFFATT, Stephen

ETATS-UNIS D'AMERIQUE
in its capacity as elected Office

Applicant's or agent's file reference
3708 PCT

Priority date (day/month/year)
06 August 1999 (06.08.99)

| | The designated Office is hereby notified of its election made: X in the demand filed with the International Preliminary Examining Authority on: 20 February 2001 (20.02.01) in a notice effecting later election filed with the International Bureau on: |
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| 2 | was not made before the expiration of 19 months from the priority date or, where Rule 32 applies, within the time limit under Rule 32.2(b). |
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The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland Authorized officer

H. Zhou

Telephone No.: (41-22) 338.83.38

Facsimile No.: (41-22) 740.14.35

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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

| Applicant's or agent's file reference | | | |
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| 3708/CT/203.24 | FOR FURTHER ACTION | Prelimina | |
| International application No. | International filing date (day/s | PCT/IPEA nonth/year) | (416) Priority date (day/month/year) |
| PCT/US00/21377 | 04 AUGUST 2000 | | 06 AUGUST 1999 |
| International Patent Classification (IPC) IPC(7): A61N 5/00; G21G 5/00 and U | or national classification and IF JS Cl.: 250/492.2 | C | |
| Applicant APPLIED MATERIAL, INC. | | | |
| 2. This REPORT consists of a t This report is also accomp been amended and are the | total of sheets. | according to | iption, claims and/or drawings which have |
| These annexes consist of a total | al of sheets. | | |
| 3. This report contains indications | s relating to the following ite | ems: | |
| I X Basis of the report | | | |
| II Priority | | | |
| III Non-establishment | of ranget with resemble | . 14 | |
| IV Lack of unity of in | | elty, inventi | ve step or industrial applicability |
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| V X Reasoned statement citations and explan | under Article 35(2) with regai ations supporting such stateme | d to novelty, ent | inventive step or industrial applicability; |
| VI Certain documents ci | ited | | |
| VII Certain defects in th | e international application | | |
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| Commissioner of Patents and Trademark | | zed officer | Sharm 2. Hoppe |
| Box PCT Washington, D.C. 20231 | | RESA ARROY | /0 |
| acsimile No. (703) 305-3230 | Telepho | ne No. (705 | 3) 308-0956 |
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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

| In | ional application No. |
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| I. B | asis of t | the report | | | · · · · · · · · · · · · · · · · · · · | | | |
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| ٳ | X the | description, pages | NONE | | | | | |
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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

| statement | | |
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| Novelty (N) | Claims | 1-40 |
| | Claims | NONE |
| Inventive Step (IS) | Claima | 1.40 |
| in the state of th | Claims Claims | NONE |
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| Industrial Applicability (IA) | Claims | 1-40 |
| | Claims | NONE |
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| e substrate on the holder, and exposing the | | ged particle. |
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INTERNATIONAL SEARCH REPORT

(PCT Article 18 and Rules 43 and 44)

| Applicant's or agent's file reference 3708 PCT | FOR FURTHER See Notification (Form PCT/ISA/ | of Transmittal of International Search Report 220) as well as, where applicable, item 5 below. |
|---|--|---|
| International application No. | International filing date (day/month/year) | (Earliest) Priority Date (day/month/year) |
| PCT/US 00/21377 Applicant | 04/08/2000 | 06/08/1999 |
| APPLIED MATERIALS, INC. 6 | et al. | |
| This International Search Report has bee according to Article 18. A copy is being to | en prepared by this International Searching Auth ransmitted to the International Bureau. | ority and is transmitted to the applicant |
| This International Search Report consists X It is also accompanied by | s of a total of sheets. y a copy of each prior art document cited in this i | eport. |
| 1. Basis of the report | | |
| With regard to the language, the language in which it was filed, un | international search was carried out on the basi less otherwise indicated under this item. | s of the international application in the |
| the international search v Authority (Rule 23.1(b)). | vas carried out on the basis of a translation of the | |
| b. With regard to any nucleotide an was carried out on the basis of the | d/or amino acid sequence disclosed in the inte | ernational application, the international search |
| contained in the internation | onal application in written form. | |
| | rnational application in computer readable form. | |
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| furnished subsequently to | this Authority in computer readble form. | |
| the statement that the sub international application a | sequently furnished written sequence listing doe s filed has been furnished. | s not go beyond the disclosure in the |
| the statement that the info | rmation recorded in computer readable form is i | dentical to the written sequence listing has been |
| Certain claims were four | nd unsearchable (See Box I). | |
| X Unity of invention is lack | • | |
| With regard to the title , | | |
| X the text is approved as sub | omitted by the applicant | |
| | ned by this Authority to read as follows: | |
| With regard to the abstract, | | |
| X the text is approved as sub | mitted by the applicant. | |
| the text has been establish | ed, according to Rule 38.2(b), by this Authority a date of mailing of this international search report, | s it appears in Box III. The applicant may, submit comments to this Authority |
| The figure of the drawings to be publis | hed with the abstract is Figure No. | 3 |
| as suggested by the application | ant. | None of the figures. |
| because the applicant failed | to suggest a figure. | |
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INTERNATIONAL SEARCH REPORT

International application No. PCT/US 00/21377

| Box I Observations where co | ertain claims were found unsearchable (Continu | |
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| | | ************************************** |
| This International Search Report has | s not been established in respect of certain claims under A | rticle 17(2)(a) for the following reasons: |
| Claims Nos.: because they relate to subjection | ect matter not required to be searched by this Authority, na | mely: |
| Claims Nos.: because they relate to parts an extent that no meaningful | of the International Application that do not comply with the International Search can be carried out, specifically: | prescribed requirements to such |
| | claims and are not drafted in accordance with the second a | |
| | y of invention is lacking (Continuation of item 2 | |
| This International Searching Authority for | ound multiple inventions in this international application, as | s follows: |
| see additional she | eet | |
| As all required additional search searchable claims. | n fees were timely paid by the applicant, this International S | Search Report covers all |
| As all searchable claims could be of any additional fee. | pe searched without effort justifying an additional fee, this A | Authority did not invite payment |
| As only some of the required add covers only those claims for which | ditional search fees were timely paid by the applicant, this ch fees were paid, specifically claims Nos.: | International Search Report |
| χ No required additional search fee | s were timely naid by the applicant of | |
| restricted to the invention first me 1-9,11-14,17,18 | es were timely paid by the applicant. Consequently, this Intentioned in the claims; it is covered by claims Nos.: | ernational Search Report is |
| mark on Protest | The additional search fees were accomp | |
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FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. Claims: 1-9,11-14,17,18

A wafer holder for retaining a substrate within a process chamber, comprising:

- an electrode, so that the wafer holder can also be called electrostatic chuck; and
- one or more layers covering a portion of the wafer holder in contact with the wafer, where at least one of the layers is compliant.

An apparatus for projecting patterned charged particles onto a substrate, comprising:

- a processing chamber;
- a charged particle source for generating a charged particle beam that impinges on the substrate; and
- an electrostatic chuck as described above.

2. Claims: 10,15,16

An apparatus for projecting patterned charged particles onto a substrate, comprising:

- a processing chamber;
- a charged particle source for generating a charged particle beam that impinges on the substrate;
- an electrostatic chuck comprising an electrode and one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant; and comprising:
- a computer for calculating an estimated charged particle beam deflection to compensate for the actual deformation of the substrate, wherein the computer generates a deflection signal corresponding to the calculated deflection;
- a beam deflector for deflecting the charged particle beam in response to the deflection signal from the computer; or comprising:
- a lithography mask between the charged particle source and the substrate;
- an electron sensor for detecting backscattered electrons;

International Application No. PCT/US 00 /21377

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

or comprising:

- a substrate temperature sensor for sending a signal corresponding to the measured substrate temperature to the computer.

3. Claims: 19-25

A method for patterning a photoresist layer on a substrate comprising the steps of:

- forming a photoresist layer on the substrate;
- positioning the substrate on an electrostatic chuck having one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant; and
- exposing portions of the photoresist layer on the substrate to a charged particle beam.

4. Claims: 26-28

An electrostatic chuck for use in substrate processing, the chuck having an electrode covered by an insulative layer for receiving the substrate, wherein the insulative layer is elastic and can withstand 10% shear stress without exceeding the material yield strength.

5. Claims: 29-35

A method for holding a wafer on a chuck having an electrode and one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant, comprising the steps of:

- placing the wafer on one of the layers of the chuck; and
- energizing the electrode.

6. Claims: 36-40

An apparatus for handling a substrate for use in semiconductor processing, comprising:

- a wafer holder; and
- one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant.

| FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210 | |
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INTERNATIONAL SEARCH REPORT

International Application No

PCT/US 00/21377 A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L21/00 According to International Patent Classification (IPC) or to both national classification and IPC **B. FIELDS SEARCHED** Minimum documentation searched (classification system followed by classification symbols) IPC 7 H01L Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal, WPI Data, PAJ, IBM-TDB, INSPEC C. DOCUMENTS CONSIDERED TO BE RELEVANT Category ° Citation of document, with indication, where appropriate, of the relevant passages Relevant to claim No. Х US 5 452 177 A (FRUTIGER WILLIAM A) 1,2,5,6, 19 September 1995 (1995-09-19) 8,9,13, 14, 26-30, 33,34, 36,37,39 Α column 4, line 40 - line 55 column 6, line 50 - line 63 column 7, line 31 - line 64 column 9, line 35 - line 50 Further documents are listed in the continuation of box C. Patent family members are listed in annex. Special categories of cited documents: "T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the "A" document defining the general state of the art which is not considered to be of particular relevance earlier document but published on or after the international "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such docudocument referring to an oral disclosure, use, exhibition or ments, such combination being obvious to a person skilled document published prior to the international filing date but in the art. later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 1 5. 06. 01 10 January 2001 Name and mailing address of the ISA Authorized officer European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016 Giordani, S

INTERNATIONAL SEARCH REPORT

International Application No PCT/US 00/21377

| Category ° | Citation of document, with indication, where appropriate, of the relevant passages | |
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| Odlegory | oration of document, with indication, where appropriate, or the relevant passages | Relevant to claim No. |
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| | column 7, line 17 -column 9, line 26 | 39,40 |



International Application No

| | | Information on patent family m | nembers | | | Application No |
|-------------------------------------|--------------|--------------------------------|--|--|---|--|
| Patent docume cited in search re | ent eport | Publication date | T | Patent family member(s) | | 00/21377 Publication |
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(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization International Bureau



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(43) International Publication Date 15 February 2001 (15.02.2001)

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(10) International Publication Number WO 01/11431 A2

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60/147,684

6 August 1999 (06.08.1999) U

(71) Applicant (for all designated States except US): AP-PLIED MATERIALS, INC. [US/US]; 3050 Bowers Avenue, Santa Clara, CA 95054 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): MOFFATT, Stephen

[GB/US]; 3544 Washington Boulevard, Jersey City, NJ 07310 (US).

(74) Agent: DERGOSITS, Michael; Dergosits & Noah LLP, Suite 1150, Four Embarcadero Center, San Francisco, CA 94111 (US).

(81) Designated States (national): JP, KP, US.

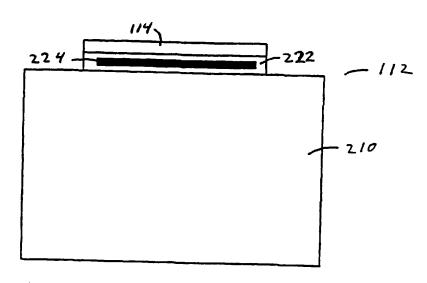
(84) Designated States (regional): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).

Published:

 Without international search report and to be republished upon receipt of that report.

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METHOD AND APPARATUS OF HOLDING SEMICONDUCTOR WAFERS FOR LITHOGRAPHY AND OTHER WAFER PROCESSES



(57) Abstract: A wafer chuck is designed to allow the substrate to thermally deform during charged particle beam lithography. The wafer chuck includes a compliant layer disposed over a chuck body. During lithography processing the wafer is electrostatically held in contact with a flexible compliant layer and the wafer is exposed to the charged particle beam resulting in thermal deformation of the wafer. The compliant layer deforms with the substrate and allows the wafer to deform in a predictable manner.

O 01/11431 A2

(19) World Intellectual Property Organization International Bureau



(43) International Publication Date 15 February 2001 (15.02.2001)

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H01L 21/00

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(30) Priority Data:

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6 August 1999 (06.08.1999) U

(71) Applicant (for all designated States except US): AP-PLIED MATERIALS, INC. [US/US]; 3050 Bowers Avenue, Santa Clara, CA 95054 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): MOFFATT, Stephen [GB/US]; 3544 Washington Boulevard, Jersey City, NJ 07310 (US). (74) Agent: DERGOSITS, Michael; Dergosits & Noah LLP, Suite 1150, Four Embarcadero Center, San Francisco, CA 94111 (US).

(81) Designated States (national): JP, KP, US.

(84) Designated States (regional): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).

Published:

with international search report

with amended claims and statement

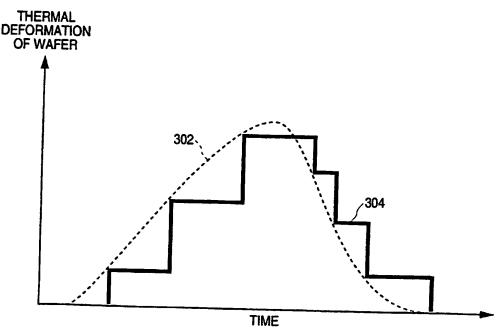
(88) Date of publication of the international search report:

15 November 2001

Date of publication of the amended claims and statement: 20 December 2001

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METHOD AND APPARATUS OF HOLDING SEMICONDUCTOR WAFERS FOR LITHOGRAPHY AND OTHER WAFER PROCESSES



(57) Abstract: A wafer chuck is designed to allow the substrate to thermally deform during charged particle beam lithography. The wafer chuck includes a compliant layer disposed over a chuck body. During lithography processing the wafer is electrostatically held in contact with a flexible compliant layer and the wafer is exposed to the charged particle beam resulting in thermal deformation of the wafer. The compliant layer deforms with the substrate and allows the wafer to deform in a predictable manner.

01/11431 43

AMENDED CLAIMS

[received by the International Bureau on 15 August 2001 (15.08.01); original claims 1 and 8 amended; remaining claims unchanged (2 pages)]

- A wafer holder for retaining a substrate within a processing chamber comprising:
 an electrode; and
- one or more layers covering a portion of the wafer holder and having a compliant

 surface for supporting the substrate which moves with the substrate in a direction parallel
 to a planar surface of the substrate when the substrate expands or contracts.
 - 2. The chuck of claim 1 wherein the compliant layer has a hardness between 25 and 100 Shore Hardness scale A.
 - 3. The chuck of claim 1 wherein the compliant layer is an insulator having a dielectric constant between 1 and 3.
- 4. The chuck of claim 1 wherein the compliant layer can withstand 10% shear stress without exceeding the yield strength of the complaint layer material.
 - 5. The chuck of claim 1 wherein the electrode comprises at least one conductive material selected from the group consisting of: copper, nickel, chromium, aluminum iron, and mixtures or alloys thereof.

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6. The chuck of claim 1 wherein the compliant layer comprises an insulative material selected from the group consisting of: fluorosilicones, polyamides,

polyketones, polyetherketones, polysulfones, polycarbonates, polystyrenes, polyurethanes, nylons, polyvinylchlorides, polypropylenes, polyetherketones, polyethersulfones, polyethylene terephthalate, fluoroethylene propylene copolymers, cellulose, triacetates, silicones and rubbers, and combinations thereof.

- The chuck of claim 1 wherein the compliant layer is between 1 and 3 μm thick.
- 8. An apparatus for projecting patterned charged particles onto a substrate comprising:
- 10 a processing chamber;
 - a charged particle source for generating a charged particle beam that impinges on the substrate; and

an electrostatic chuck comprising an electrode and one or more layers covering a portion of the wafer holder and having a compliant surface for supporting the substrate which moves with the substrate in a direction parallel to a planar surface of the substrate when the substrate expands or contracts.

- 9. The apparatus of claim 8 wherein the compliant layer has a hardness between 25 and 100 Shore Hardness scale A.
- 10. The apparatus of claim 8 further comprising:
- a computer for calculating an estimated charged particle beam deflection to compensate for the actual deformation of the substrate caused by the exposure of the

STATEMENT UNDER ARTICLE 19 (1)

In the International Search Report, the Examiner cited several references as being of particular relevance alone. All of these references disclose an electrostatic wafer support having an insulative layer which contacts the substrate. Applicant submits that although some of the cited references disclose a vertically compressible insulative layer, none of the references disclose a compliant layer that moves with the substrate in a direction parallel to a planar surface of the substrate as the substrate expands or contracts. In particular, during wafer processing, the temperature of the substrate tends to increase resulting in thermal expansion. A substrate surface is required which is mechanically stable elevated temperatures and sufficiently elastic to move with the expanding and contracting substrate.

The Examiner cited U.S. Patent Nos. 5,883,778, 5,729,423, 5,452,177, 5,310,453, 4,665,463, and European Patent Nos. 0856882 and 0692814, each as being of particular relevance alone. The applicant submits that while the references disclose a layer having vertical compliance, none of the references disclose a layer on a wafer holder having a compliant surface for supporting a substrate that expands or contracts in a direction parallel to the planar surface of the substrate.

III. Conclusion

It is respectfully submitted that the amended claims included on the attached substitute pages are novel and involve an inventive step that is not obvious to one skilled in the art in light of the cited references, either alone or in combination. It is further respectfully submitted that the amendments made to the claims do not amend or otherwise impact the description and drawings as originally filed.